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TRANSMITTAL	Filing Date	September 5, 2003					
FORM	First Named Inventor	John P. Daley					
	Art Unit	2812					
	Examiner Name	Unknown					
(to be used for all correspondence after initial							
Total Number of Pages in This Submission	Attorney Docket Numb	MI22-2380					
ENCLOSURES (Check all that apply)							
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Fee Attached	Licensing-related Papers	Appeal Communication to Board of Appeals and Interferences					
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After Final	Petition to Convert to a Provisional Application Power of Attorney, Revoc	Proprietary Information					
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Supplemental Information Disclosure Statement	CD, Number of CD(s)	cited foreign patent and articles					
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Date October 25, 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Pater Application Serial No	10/655,997
Filing Date	September 5, 2003
Pater Application Serial NoFiling Date	Jon P. Daley
Assignee	Micron Technology, Inc.
Group Art Unit '	
Examiner	
Attorney Docket No	MI22-2380
Customer No	
Title: Methods of Forming Patterned Pho Substrates	toresist Layers over Semiconductor

INFORMATION DISCLOSURE STATEMENT

References -- See Attached Form PTO-1449

The attached form PTO-1449 is submitted in compliance with 37 CFR §1.56. Pursuant to 1276 OG 55, August 5, 2003, no copies of cited U.S. patents or U.S. patent application publications are included, as the date of filing of this patent application occurs after June 30, 2003. Copies of all other references are attached. No admission is made regarding whether all the listed references are prior art.

Citation of the referenced art is respectfully requested.

This Supplemental Information Disclosure Statement is being filed before the mailing date of a first Office Action. There, no fee is believed to be required. However, in the event that a fee is required for filing this Information Disclosure Statement, please charge the fee specified under 37 C.F.R. § 1.17(p) to Deposit Account No. 23-0925.

Respectfully submitted,

Dated: 10-25-69

Mark S. Matkin

Reg. No. 32,268

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OCT 25	2004	40			FILING DATE September 5, 2003			GROUP 2812		
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	AN	Lemberger et a novel MOCVD	ıl., Electrical ch precursors, M	haracterization and reliab licroelectronic Engineering	ility aspects of zirog (2004), pages 3	conium si 315-320	ilicate	films o	btained fr	rom
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